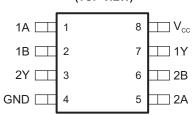


### FEATURES

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V .
- Max  $t_{pd}$  of 4.9 ns at 3.3 V
- Low Power Consumption, 10-µA Max Icc
- ±24-mA Output Drive at 3.3 V ٠
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC}$  = 3.3 V, T<sub>A</sub> = 25°C

DCT PACKAGE (TOP VIEW)



Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C

- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 1000-V Charged-Device Model (C101)

I		ACKAGE VIEW)	E		AGE IEW)	
1A∐ 1B ∐	1 2	8 7	∏ V <sub>cc</sub> ∏ 1Y	GND 2Y 1B	O 4 5 O O 3 6 O O 2 7 O	2A 2B 1Y
GND []	3 4	6 5	⊥ 2B ∏ 2A	1A	O180	V <sub>cc</sub>

See mechanical drawings for dimensions.

# DESCRIPTION/ORDERING INFORMATION

This dual 2-input positive-NOR gate is designed for 1.65-V to 5.5-V V<sub>CC</sub> operation.

The SN74LVC2G02 performs the Boolean function  $Y = \overline{A + B}$  or  $Y = \overline{A} \cdot \overline{B}$  in positive logic.

NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(2)</sup>	
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC2G02YZPR	CB_	
–40°C to 85°C	SSOP – DCT	Reel of 3000	SN74LVC2G02DCTR	C02	
	Reel of 300		SN74LVC2G02DCUR	000	
	VSSOP – DCU	Reel of 250	SN74LVC2G02DCUT	C02_	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. (2)DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

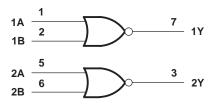


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#### **FUNCTION TABLE** (EACH GATE)

INPL	INPUTS					
Α	В	Y				
Н	Х	L				
х	Н	L				
L	L	Н				

#### LOGIC DIAGRAM (POSITIVE LOGIC)



# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
VI	Input voltage range <sup>(2)</sup>		-0.5	6.5	V
Vo	Voltage range applied to any output in t	he high-impedance or power-off state <sup>(2)</sup>	-0.5	6.5	V
Vo	Voltage range applied to any output in t	he high or low state <sup>(2)(3)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through V <sub>CC</sub> or GNI	)		±100	mA
		DCT package		220	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCU package		227	°C/W
		YZP package		$\begin{array}{c c} -0.5 & 6.5 \\ \hline -0.5 & 6.5 \\ \hline -0.5 & V_{CC} + 0.5 \\ \hline & -50 \\ \hline & -50 \\ \hline \pm 50 \\ \hline \pm 100 \\ \hline & 220 \\ \end{array}$	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
 (4) The package thermal impedance is calculated in accordance with JESD 51-7.

SCES194L-APRIL 1999-REVISED JANUARY 2007

# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
v	Supply voltogo	Operating	1.65	5.5	V
V <sub>CC</sub>	Supply voltage	$\begin{tabular}{ c c c c } \hline $$ $$ $$ $$ $$ $$ $$ $$ $$ $$ $$ $$ $$		v	
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65  imes V_{CC}$		
V	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V
VIH	High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		V
		$V_{CC} = 4.5 V \text{ to } 5.5 V$	$0.7  imes V_{CC}$		
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
VIL	Input voltage Output voltage	$V_{CC} = 3 V \text{ to } 3.6 V$		0.8	v
		$V_{CC} = 4.5 V \text{ to } 5.5 V$		$0.3  imes V_{CC}$	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-4	
		V <sub>CC</sub> = 2.3 V		-8	
I <sub>ОН</sub>	H    High-level input voltage      L    Low-level input voltage      Input voltage    Output voltage      Output voltage    Output voltage      H    High-level output current      L    Low-level output current      L    Low-level output current      Δv    Input transition rise or fall rate			-16	mA
		$V_{CC} = 3 V$		-24	
		V <sub>CC</sub> = 4.5 V		-32	
		V <sub>CC</sub> = 1.65 V		4	
		V <sub>CC</sub> = 2.3 V		8	
I <sub>OL</sub>	Low-level output current			16	mA
	$I_{IL}$ Low-level input voltage $I_{IL}$ Input voltage $I_{IL}$ Input voltage $I_{IL}$ Output voltage $I_{OL}$ High-level output current $D_{H}$ Low-level output current $D_{L}$ Low-level output current $t/\Delta v$ Input transition rise or fall rate	$V_{CC} = 3 V$		24	
		V <sub>CC</sub> = 4.5 V		32	
		$V_{CC}$ = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC}$ = 5 V ± 0.5 V		5	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP <sup>(1)</sup>	MAX	UNIT
	I <sub>OH</sub> = -100 μA	1.65 V to 5.5 V	V <sub>CC</sub> – 0.1		
	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
N/	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9		V
V <sub>он</sub>	$I_{OH} = -16 \text{ mA}$	- 3 V	2.4		v
	$I_{OH} = -24 \text{ mA}$	3V	2.3		
	$I_{OH} = -32 \text{ mA}$	4.5 V			
	I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V		0.1	
	I <sub>OL</sub> = 4 mA	1.65 V		0.45	
N/	I <sub>OL</sub> = 8 mA	2.3 V		0.3	V
V <sub>OL</sub>	I <sub>OL</sub> = 16 mA	- 3 V		0.4	
	I <sub>OL</sub> = 24 mA	3V		0.55	
	I <sub>OL</sub> = 32 mA	4.5 V		0.55	
I <sub>I</sub> A or B inputs	$V_{I} = 5.5 \text{ V or GND}$	0 to 5.5 V		±5	μA
l <sub>off</sub>	$V_{I}$ or $V_{O} = 5.5 V$	0		±10	μA
I <sub>CC</sub>	$V_{I} = 5.5 \text{ V or GND}, \qquad I_{O} = 0$	1.65 V to 5.5 V		10	μA
$\Delta I_{CC}$	One input at $V_{CC} - 0.6 V$ , Other inputs at $V_{CC}$ or GND	3 V to 5.5 V		500	μA
Ci	$V_{I} = V_{CC} \text{ or } GND$	3.3 V	5		pF

(1) All typical values are at V<sub>CC</sub> = 3.3 V,  $T_A = 25^{\circ}C$ .

#### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

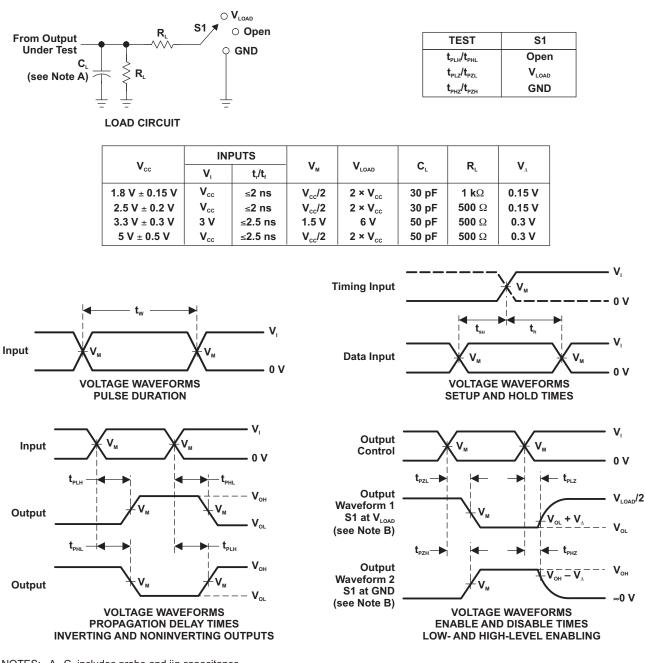
Ī	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		$V_{CC}$ = 2.5 V $\pm$ 0.2 V		$V_{CC} = 3.3 V \\ \pm 0.3 V$		V <sub>CC</sub> = 5 V ± 0.5 V		UNIT
		(INFUT)	(001F01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Ī	t <sub>pd</sub>	A or B	Y	3.2	8.9	1	5.4	1	4.9	1	4.4	ns

## **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

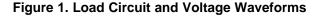
PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	$V_{CC} = 5 V$	UNIT	
		TEST CONDITIONS	TYP	ТҮР	ТҮР	TYP		
C	Power dissipation capacitance	f = 10 MHz	18	18	19	22	pF	

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_{\scriptscriptstyle L}$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{\mbox{\tiny PLZ}}$  and  $t_{\mbox{\tiny PHZ}}$  are the same as  $t_{\mbox{\tiny dis}}$
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{od}$ .
- H. All parameters and waveforms are not applicable to all devices.



### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74LVC2G02DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G02DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G02DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G02DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G02DCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G02DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G02DCUTE4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G02DCUTG4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC2G02YZPR	ACTIVE	DSBGA	YZP	8	3000	TBD	Call TI	Call TI

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### OTHER QUALIFIED VERSIONS OF SN74LVC2G02 :

Enhanced Product: SN74LVC2G02-EP

# PACKAGE OPTION ADDENDUM



27-Nov-2008

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

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## TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



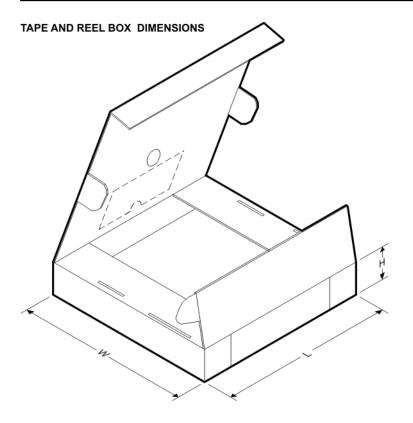
*All dimensions are nominal	
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Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2G02DCUR	US8	DCU	8	3000	180.0	9.2	2.25	3.35	1.05	4.0	8.0	Q3



# PACKAGE MATERIALS INFORMATION

26-Nov-2008



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2G02DCUR	US8	DCU	8	3000	202.0	201.0	28.0

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

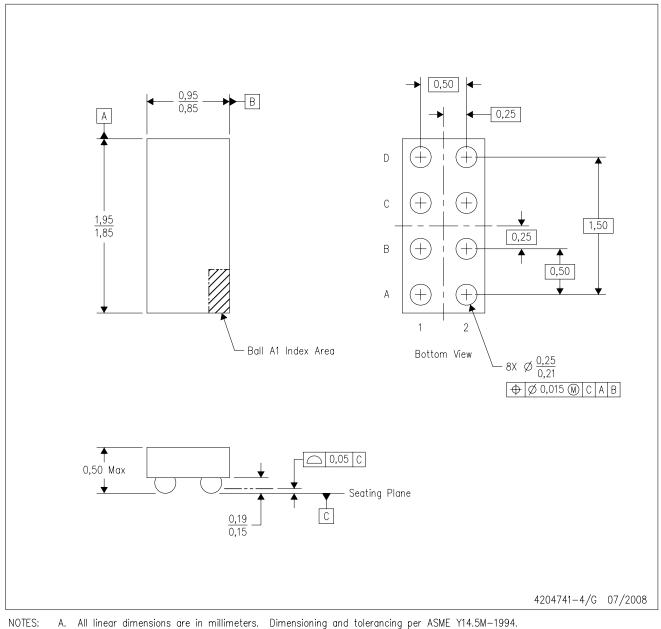
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

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# **MECHANICAL DATA**

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

#### DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



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